



PS7904-1A

Preliminary Data Sheet

Specifications in this document are tentative and subject to change.

OCMOS FET

4-PIN SMALL FLAT-LEAD, LOW ON-STATE RESISTANCE

1-ch Optical Coupled MOS FET

Mar 7, 2012

DESCRIPTION

The PS7904-1A is a low output capacitance solid state relay containing a GaAs LED on the light emitting side (input side) and MOS FETs on the output side.

A small flat-lead package has been provided which realizes a reduction in mounting area of about 50% compared with the PS78xx series.

It is suitable for high-frequency signal control, due to its low C R, low output capacitance, and low off-state leakage current.

FEATURES

Small flat-lead package (2.5 (L) 2.3 (W) 2.9 (H) mm)

Low C R (C R = $29.7 pF \cdot$)

Low on-state resistance ($R_{on} = 1.1$ TYP.)

Large continuous load current (I_L = 400 mA)

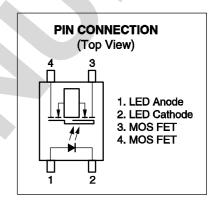
1 channel type (1 a output)

Designed for AC/DC switching line changer

Low offset voltage

Embossed tape product: PS7904-1A-F3 : 3 500 pcs/reel

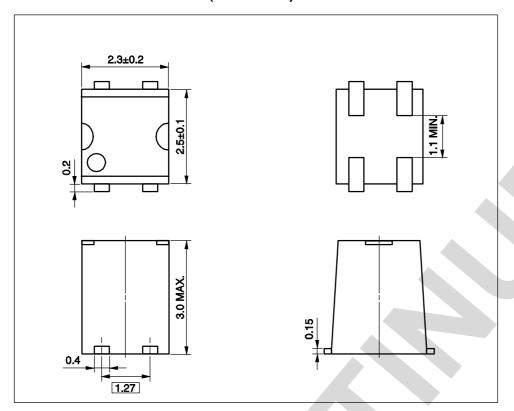
Pb-Free product



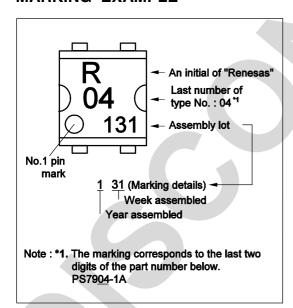
APPLICATIONS

Measurement equipment

PACKAGE DIMENSIONS (UNIT: mm)



MARKING EXAMPLE





ABSOLUTE MAXIMUM RATINGS (T_A = 25\(\mathbb{M}C\), unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	I _F	50	mA	
	Reverse Voltage	V_{R}	5.0	V	
	Power Dissipation	P_D	50	mW	
	Peak Forward Current *1	I _{FP}	1	А	
MOS FET	Break Down Voltage	V_L	60	V	
	Continuous Load	lι	400	mA	
	Current				
	Pulse Load Current *2	I _{LP}	800	mA	
	(AC/DC Connection)			4	
	Power Dissipation *2	P_D	250	mW	
Isolation Voltage *3		BV	500	Vr.m.s.	
Total Power Dissipation		P⊤	300	mW	
Operating Ambient Temperature		T _A	40 to +85	С	
Storage Temperature		T _{stg}	40 to +100	С	

Notes: *1. PW = 100 s, Duty Cycle = 1%

RECOMMENDED OPERATING CONDITIONS (TA = 25 C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	l _F	4.5	5	20	mA
LED Off Current	l _F	0.1			mA

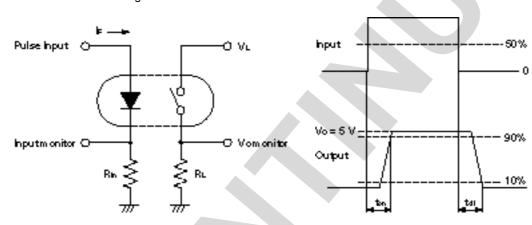
^{*2}. PW = 100 ms, 1 shot

^{*3.} AC voltage for 1 minute at T_A = 25 C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS ($T_A = 25 \boxtimes C$)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_{F}	I _F = 5 mA		1.1	1.4	V
	Reverse Current	I _R	V _R = 5 V			5.0	Α
MOS FET	Off-state Leakage Current	I _{Loff}	V _L = 60 V		0.1	10	nA
	Output Capacitance	Cout	$V_L = 0 V, f = 1 MHz$		27	35	pF
Coupled	LED On-state Current	I _{Fon}	I _L = 400 mA			4.0	mA
	On-state Resistance	R _{on}	$I_F = 5 \text{ mA}, I_L = 400 \text{ mA},$ t 10 ms		1.1	1.5	
	Turn-on Time*1	t _{on}	$I_F = 5 \text{ mA}, V_O = 5 \text{ V},$		0.15	0.5	ms
	Turn-off Time*1	t _{off}	$R_L = 500$, PW 1 ms		0.15	0.5	
	Isolation Resistance	R _{I-O}	$V_{I-O} = 0.5 \text{ kV}_{DC}$	10 ⁹			
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.3		pF

Notes: *1. Test Circuit for Switching Time



USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- **2.** Avoid storage at a high temperature and high humidity.



Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- · Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

